



University School of Basic & Applied Sciences **Dr. SATYABRATA MOHAPATRA**
Guru Gobind Singh Indraprastha University **Ph.D (Physics)**
Sector 16C, Dwarka, New Delhi 110075, INDIA **Assistant Professor**
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Applications are invited for the post of one **Junior Research Fellow (JRF)** for a Inter University Accelerator Centre (IUAC), New Delhi Research project in University School of Basic and Applied Sciences (USBAS), Guru Gobind Singh Indraprastha University, New Delhi 110075.

Title of Project: **“Study on effects of metal impurities on swift heavy ion beam induced epitaxial crystallization of amorphous silicon”**

Tenure: Tenable up to July 2012.

Qualification: M.Sc. (Physics/Applied Physics/Materials Science) with minimum 55% marks. (Note: NET/GATE qualified candidates will be preferred).

Fellowship for JRF: Rs. 8000/- p.m. for candidates without NET and
Rs. 12,000/- p.m. for NET qualified candidates.

The candidate would be required to carry out experiments at IUAC, New Delhi, IOP, Bhubaneswar and USBAS, Guru Gobind Singh Indraprastha University, New Delhi. The candidate would be encouraged to work for his/her Ph.D.

Applications on plain paper along with CV and supporting documents may be sent by post or email to **Dr. Satyabrata Mohapatra, Principal Investigator, University School of Basic and Applied Sciences, Guru Gobind Singh Indraprastha University, Sector 16C, Dwarka, New Delhi 110075 latest by 8th March 2011.**

Interview will be conducted on **17th March 2011** at 10.30 a.m. in USBAS, Guru Gobind Singh Indraprastha University, Sector 16 C, Dwarka, New Delhi 110075.

Short listed candidates will be called for interview. Candidates must bring original certificates/supporting documents and their photocopy. No TA/DA will be provided for appearing in the interview.

Dr. Satyabrata Mohapatra
Principal Investigator